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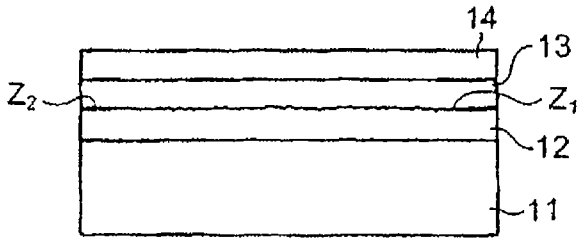
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(54) Title: DETACHABLE SUBSTRATE OR DETACHABLE STRUCTURE AND METHOD FOR THE PRODUCTION THEREOF

(54) Titre : SUBSTRAT OU STRUCTURE DEMONTABLE ET PROCEDE DE REALISATION




(57) Abstract: The invention relates to the preparation of a thin layer comprising a step in which an interface is created between a layer used to create said thin layer and a substrate, characterized in that said interface is made in such a way that it is provided with at least one first zone (Z1) which has a first level of mechanical strength, and a second zone (Z2) which has a level of mechanical strength which is substantially lower than that of the first zone. Said interface can be created by glueing surfaces which are prepared in a differentiated manner, by a layer which is buried and embrittled in a differentiated manner in said zones, or by an intermediate porous layer.

(57) Abrégé : Le procédé de préparation d'une couche mince comportant une étape de réalisation d'un interface entre une couche destinee a faire de cette couche mince et un substrat est caractérisé en ce que cet interface est realisé en sorte d'avoir au moins une première zone (Z1) ayant un premier niveau de teneur mécanique sensiblement inférieur au premier niveau de tenue mécanique. Cette interface peut notamment être constituée par le collage de surfaces préparées de façons différenciées, par une couche enterrée fragilisée de façon différenciée dans ces zones, ou rpar une couche intermédiaire poreuse.

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